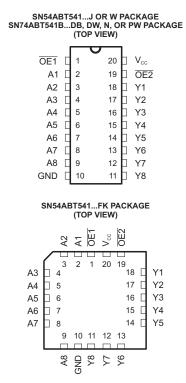


FEATURES

- State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C
- High-Impedance State During Power Up and Power Down
- High-Drive Outputs (–32-mA I_{OH}, 64-mA I_{OL})
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), Ceramic Flat (W) Package, and Plastic (N) and Ceramic (J) DIPs



DESCRIPTION/ORDERING INFORMATION

The SN54ABT541 and SN74ABT541B octal buffers and line drivers are ideal for driving bus lines or buffering memory address registers. The devices feature inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

ORDERING INFORMATION

T _A	PAC	KAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Reel of 1000	SN74ABT541BN	SN74ABT541BN
	SOIC - DW	Tube of 25	SN74ABT541BDW	ADTE 44D
	201C – DW	Reel of 2000	SN74ABT541BDWR	- ABT541B
-40°C to 85°C	SSOP – DB	Reel of 2000	SN74ABT541BDBR	- AB541B
	330P - DB	Reel of 2000	SN74ABT541BDBRG4	AD341D
	TSSOP – PW	Reel of 1050	SN74ABT541BPW	- AB541B
	1330F - FW	Reel of 2000	SN74ABT541BPWR	AD341D
	CDIP – J	Reel of 1000	SNJ54ABT541J	SNJ54ABT541J
–55°C to 125°C	CFP – W	Reel of 510	SNJ54ABT541W	SNJ54ABT541W
	LCCC – FK	Reel of 2200	SNJ54ABT541FK	SNJ54ABT541FK

 Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

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EPIC-IIB is a trademark of Texas Instruments.



DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The 3-state control gate is a two-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all eight outputs are in the high-impedance state.

When VCC is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, $\overline{\text{OE}}$ should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT541 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT541B is characterized for operation from –40°C to 85°C.

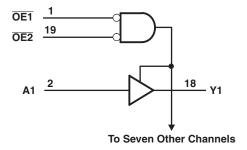
FUNCTION TABLE

	INPUTS	OUTPUTS	
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	X	Χ	Z
X	Н	Χ	Z

LOGIC SYMBOL(1) ΕN OE1 19 OE2 2 18 Α1 **Y1** 3 17 **A2 Y2** 16 4 **Y3 A3** 5 15 6 14 7 13 **A6 Y6** 12 8 **Y7** 9 11 **Y8 A8**

(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

LOGIC DIAGRAM (POSITIVE LOGIC)





SN54ABT541, SN74ABT541B OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

Absolute Maximum Ratings⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the high o	r power-off state	-0.5	5.5	V
Io	Current into any output in the low state	SN54ABT541		96	mA
		SN74ABT541B		128	IIIA
I _{IK}	Input clamp current	V ₁ < 0		-18	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
θ_{JA}	Package thermal impedance (3)	DB package		115	
		DW package		97	°C/W
		N package		67	C/VV
		PW package		128	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

Recommended Operating Conditions(1)

over recommended operating free-air temperature range (unless otherwise noted)

		SN54ABT5	i41	SN74ABT54	1B	UNIT
		MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
I _{OH}	High-level output current		-24		-32	mA
I _{OL}	Low-level output current		48		64	mA
Δt/Δν	Input transition rise or fall rate		5		5	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate			200		μs/V
T _A	Operating free-air temperature	-55	125	-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

SN54ABT541, SN74ABT541B OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCBS093L-DECEMBER 1993-REVISED DECEMBER 2006



Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST COMP	TIONS		T _A = 25°	С	SN54A	BT51	SN74AB	T541B	LINUT
PARAMETER	TEST CONDI	HONS	MIN	TYP ⁽¹⁾	MAX	MIN	MAX	MIN	MAX	UNIT
V _{IK}	$V_{CC} = 4.5 \text{ V},$	$I_1 = -18 \text{ mA}$			-1.2		-1.2		-1.2	V
V _{OH}	$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5		
	V _{CC} = 5 V,	$I_{OH} = -3 \text{ mA}$	3			3		3		V
	V _{CC} = 4.5 V,	$I_{OH} = -24 \text{ mA}$	2			2				V
		$I_{OH} = -32 \text{ mA}$	2(2)					2		
V _{OL}	$V_{CC} = 4.5 \text{ V},$	I _{OL} = 48 mA			0.55		0.55			VV
		$I_{OL} = 64 \text{ mA}$			0.55(2)				0.55	VV
V _{hys}				100						mV
I _I	V _{CC} = 5.5 V,	$V_I = V_{CC}$ or GND			±1		±1		±1	μΑ
I _{OZPU}	$V_{CC} = 0$ to 2.1 V, $V_{O} = 0.5$	√ to 2.7 V, OE = X			±50 ⁽³⁾		±50 ⁽³⁾		±50	μΑ
I _{OZPD}	$V_{CC} = 2.1 \text{ V to } 0, V_{O} = 0.5 \text{ V}$	√ to 2.7 V, OE = X			±50 ⁽³⁾		±50(3)		±50	μΑ
I _{OZH}	$V_{CC} = 5.5 \text{ V},$	V _O = 2.7 V			10		10		10	μΑ
I _{OZL}	V _{CC} = 5.5 V,	V _O = 0.5 V			-10		-10		-10	μΑ
I _{off}	$V_{CC} = 0 V$,	V _I or V _O ≤ 4.5 V			±100				±100	μΑ
I _{CEX}	$V_{CC} = 5.5 \text{ V}, V_{O} = 5.5 \text{ V},$	Outputs high			50				50	μΑ
Io	$V_{CC} = 5.5 V^{(4)},$	V _O = 2.5 V	-50	-140	-180	-50	-180	-50	-180	mA
I _{CC}	$V_{CC} = 5.5 \text{ V},$	Outputs high		5	250		250		250	μΑ
	$I_O = 0 \text{ V},$ $V_I = V_{CC} \text{ or GND}$	Outputs low		22	30		30		30	mA
	V1 = V00 01 014B	Outputs disabled		1	250		250		250	μΑ
ΔI_{CC}	V _{CC} = 5.5 V,	Outputs enabled			1.5		1.5		1.5	mA
	One input at 3.4 V, Other inputs at V _{CC} or	Outputs disabled			50		50		50	μΑ
	GND ⁽⁵⁾	Control Inputs			1.5		1.2		1.5	mA
C _i	V _I = 2.5 V or 0.5 V			3						pF
C _o	V _O = 2.5 V or 0.5 V			6						pF

All typical values are at V_{CC} = 5 V.
 On products compliant to MIL-PRF-38535, this parameter does not apply.
 On products compliant to MIL-PRF-38535, this parameter is not production tested.
 Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

⁽⁵⁾ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

SN54ABT541, SN74ABT541B OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

Switching Characteristics, SN54ABT541

over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO		CC = 5 V, A = 25°C				UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	
t _{PLH}	^	V	1	2.6	4.1	1	4.6	no
t _{PHL}	A	ī	1	2.9	4.2	1	4.7	ns
t _{PZH}	ŌĒ	V	1.1	3.1	4.8	1.1	5.4	
t _{PZL}	OE .	Ť	2.1	4.4	5.9	2.1	7	ns
t _{PHZ}	- OE	V	2.1	5.1	6.6	2.1	7.5	no
t _{PLZ}	OE .	Ť	1.7	4.7	6.2	1.7	6.7	ns

Switching Characteristics, SN74ABT541B

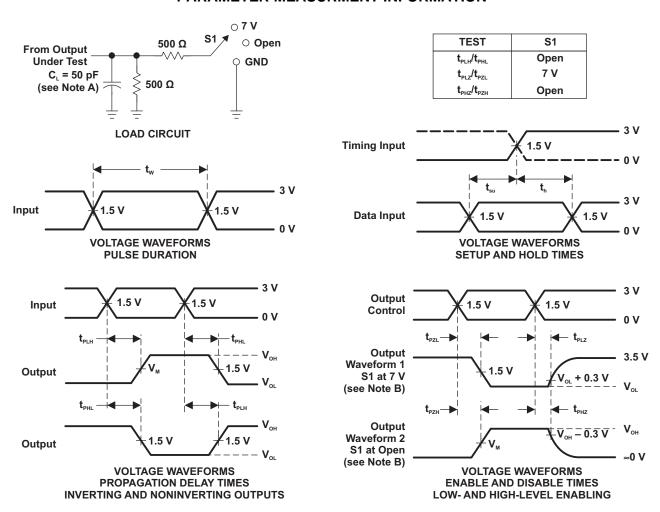
over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)		CC = 5 V, A = 25°C				UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	
t _{PLH}	۸	V	1	2	3.2	1	3.9	20
t _{PHL}	Α	ř	1	2.6	3.5	1	3.9	ns
t _{PZH}	ŌĒ	V	2	3.5	4.5	2	4	20
t _{PZL}	OE	Y	1.9	4	5.1	1.9	5.9	ns
t _{PHZ}	ŌĒ	V	2.2	4.4	5.4	2.2	5.8	20
t_{PLZ}	OE	T	1.5	3	4	1.5	4.4	ns
t _{sk(o)} ⁽¹⁾					0.5		0.5	ns

⁽¹⁾ Skew between any two outputs of the same package switching in the same direction.



PARAMETER MEASURMENT INFORMATION



NOTES: A. C. includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_o = 50 \, \Omega$, $t_i \leq 2.5 \, \text{ns}$, $t_i \leq 2.5 \, \text{ns}$.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
5962-9471801Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9471801Q2A SNJ54 ABT541FK	Samples
5962-9471801QRA	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9471801QR A SNJ54ABT541J	Samples
5962-9471801QSA	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9471801QS A SNJ54ABT541W	Samples
SN74ABT541BDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB541B	Samples
SN74ABT541BDBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB541B	Samples
SN74ABT541BDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB541B	Samples
SN74ABT541BDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT541B	Samples
SN74ABT541BDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT541B	Samples
SN74ABT541BDWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT541B	Samples
SN74ABT541BDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT541B	Samples
SN74ABT541BN	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74ABT541BN	Samples
SN74ABT541BNSR	ACTIVE	so	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT541B	Samples
SN74ABT541BPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB541B	Samples
SN74ABT541BPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB541B	Samples
SN74ABT541BPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB541B	Samples



PACKAGE OPTION ADDENDUM

24-Aug-2018

Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SNJ54ABT541FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9471801Q2A SNJ54 ABT541FK	Samples
SNJ54ABT541J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9471801QR A SNJ54ABT541J	Samples
SNJ54ABT541W	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9471801QS A SNJ54ABT541W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

24-Aug-2018

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OTHER QUALIFIED VERSIONS OF SN74ABT541B:

Automotive: SN74ABT541B-Q1

● Enhanced Product: SN74ABT541B-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All dimensions are nominal												
Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ABT541BDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74ABT541BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74ABT541BNSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74ABT541BPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ABT541BDBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74ABT541BDWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ABT541BNSR	SO	NS	20	2000	367.0	367.0	45.0
SN74ABT541BPWR	TSSOP	PW	20	2000	367.0	367.0	38.0

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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